Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-494-4914

Glass	Material:
Overall L	ength-
	0.195 inches and 0.350 inches
Terminal	
1.000 incl	
Overall D	
	0.215 inches and 0.265 inches
	e Internally-electrically Connected To Case:
Cathode	a memany-electrically connected to case.
	I Method:
Terminal	
	Provided:
	ally sealed case
	ductor Material:
Silicon	
	Rating In Volts Per Characteristic:
	lator voltage
-	olerance In Percent:
-5.0/+5.0	
	Rating Per Characteristic:
	iamperes all primaries horsepower metric and 162.00 milliamperes repetitive peak forward current
	ating Per Characteristic:
	small-signal input power, common-collector preset
	o Operating Tempurature Per Measurement Point:
	rees celsius ambient air
Test Data	Document:
81349-mil	-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
	xcludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
	ental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
	Type And Quantity:
2 uninsula	ated wire lead
Shelf Life	
N/a	
Unit Of M	leasure:
Demilitar	ization:
No	
Fiig:	
A110a0	
Mil-std (n	nilitary Standard):
Mil-prf-19	500 spec.